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10/624 357

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**
(Use several sheets if necessary)

APPLICANT
Aaron Scott Lukas, et al.

(37 CFR 1.98(b))

FILING DATE **7/21/03**

GROUP **2813**

U.S. PATENT DOCUMENTS

EXAM- INER INITIAL		DOCUMENT NUMBER							DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
NB		4	6	0	3	1	6	8	7/29/1986	S. Sasaki, et al.	522	18	2/19/1985
NB		5	6	0	9	9	2	5	3/11/1997	R. C. Camilletti, et al.	427	503	12/4/1995
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NB		6	0	1	7	8	0	6	1/25/2000	K. C. Harvey	438	475	7/28/1998
NB		6	0	4	2	9	9	4	3/28/2000	J. Yang, et al.	430	296	1/8/1999
NB		6	1	6	8	9	8	0	1/2/2001	S. Yamazaki, et al.	438	162	9/26/1996
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		DOCUMENT NUMBER							DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
													YES	NO
NB	WO	9	7	0	0	5	3	5		World			X	
NB	WO	02	0	6	5	5	3	4		World			X	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

NB		E. G. Parada, et al., "Improvement of Silicon Oxide Film Properties by Ultraviolet Excimer Lamp Annealing," Applied Surface Science 86, pp. 294-298 (1995).
NB		A. Guo, et al., "Highly Active Visible-Light Photocatalysts for Curing a Ceramic Precursor," Chem Mater. 10, pp. 531-536 (1998).
NB		T. Clark, Jr., et al., "A New Application of UV-Ozone Treatment in the Preparation of Substrate-Supported, Mesoporous Thin Films," Chem. Mater. 12, pp. 3879-3884 (2000).
NB		M. Brinkmann, et al., "Room-Temperature Synthesis of a-SiO ₂ Thin Films by UV-Assisted Ozonolysis of a Polymer Precursor," Chem. Mater. 13, pp. 967-972 (2001).
NB		A. Hozumi, et al., "Low-Temperature Elimination of Organic Components from Mesoporous Organic-Inorganic Composite Films Using Vacuum Ultraviolet Light," Chem. Mater. 12, pp. 3842-3847 (2000).
NB		M. Ouyang, et al., "Conversion of Some Siloxane Polymers to Silicon Oxide by UV/Ozone Photochemical Processes," Chem. Mater. 12, pp. 1591-1596 (2000).
NB		Q. Han, et al., "Ultra Low-k Porous Silicon Dioxide Films from a Plasma Process," IEEE (2001), pp. 171-173.
NB		C. Waldfried, et al., "Single Wafer RapidCuring™ of Porous Low-k Materials," IEEE (2002), pp. 226-228.

EXAMINER

Nema Bereznay

DATE CONSIDERED

11-30-04

EXAMINER: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



PTO/SB/08A (08-03)
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Substitute for form 1449/PTO				Complete If Known	
				Application Number	10/624,357
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Filing Date	July 21, 2003
				First Named Inventor	Aaron Scott Lukas, et al.
				Art Unit	2813
				Examiner Name	Berezny, Nema O.
Sheet	1	of	1	Attorney Docket Number	06381P USA

U. S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
DS		US- 5,935,646	08-10-1999	Raman, et al.	
		US- 6,231,989	05-15-2001	Chung, et al.	
		US- 6,426,236	07-30-2020	Ishizaka, et al.	7/2002
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		US- 2003/0003288	01-02-2003	Nakata, et al.	
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		US- 2003/0162034	08-28-2003	O'Neill, et al.	
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		US-			
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				

Examiner Signature	DS	Date Considered	11/4/06
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